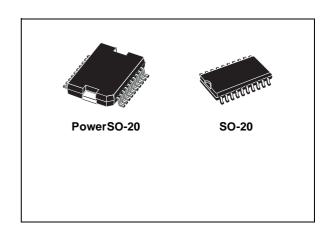




LNBP SUPPLY AND CONTROL IC WITH STEP-UP CONVERTER AND I²C INTERFACE

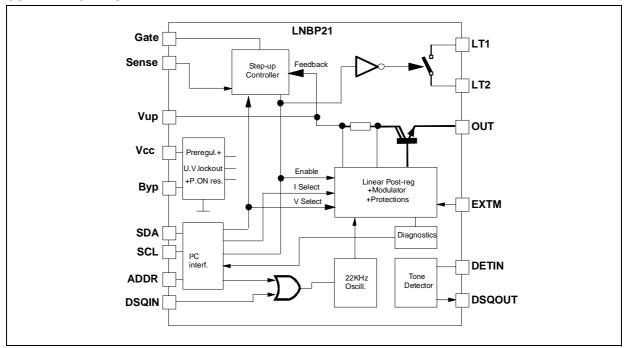
- COMPLETE INTERFACE BETWEEN LNB AND I2CTM BUS
- BUILT-IN DC/DC CONTROLLER FOR SINGLE 12V SUPPLY OPERATION
- ACCURATE BUILT-IN 22KHz TONE OSCILLATOR
- SUITS WIDELY ACCEPTED STANDARDS
- FAST OSCILLATOR START-UP FACILITATES DISEqCTM ENCODING
- BUILT-IN 22KHz TONE DETECTOR SUPPORTS BI-DIRECTIONAL DISEGCTM
- LOOP-THROUGH FUNCTION FOR SLAVE OPERATION
- LNB SHORT CIRCUIT PROTECTION AND DIAGNOSTIC
- CABLE LENGTH DIGITAL COMPENSATION
- INTERNAL OVER TEMPERATURE PROTECTION
- ESD RATING 4KV ON POWER INPUT-OUTPUT PINS



DESCRIPTION

Intended for analog and digital satellite STB receivers/SatTV, sets/PC cards, the LNBP21 is a monolithic voltage regulator and interface IC, assembled in SO-20 and PowerSO-20, specifically designed to provide the power and the 13/18V, 22KHz tone signalling to the LNB

SCHEMATIC DIAGRAM



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downconverter in the antenna or to the multiswitch box. In this application field, it offers a complete solution with extremely low component count, low power dissipation together with simple design and I^2CTM standard interfac-ing.

This IC has a built in DC/DC step-up controller that, from a single supply source ranging from 8 to 15V, generates the voltages that let the linear post-regulator to work at a minimum dissipated power. An UnderVoltage Lockout circuit disable the whole circuit when the supplied V_{CC} drops below a fixed threshold (6.7V typically). The internal 22KHz tone generator is factory trimmed in accordance to the standards, and can be controlled either by the I²CTM interface or by a dedicated pin (DSQIN) that allows immediate DiSEqCTM data encoding (*). All the functions of this IC are controlled via I²CTM bus by writing 6 bits on the System Register (SR, 8 bits). The same register can be read back, and two bits will report the diagnostic status. When the IC is put in Stand-by (EN bit LOW), the power blocks are disabled and the loop-through switch between LT1 and LT2 pins is closed, thus leaving all LNB powering and control functions to the Master Receiver (**). When the regulator blocks are active (EN bit HIGH), the output can be logic controlled to be 13 or 18 V (typ.) by mean of the VSEL bit (Voltage SELect) for remote controlling of non-DiSEqC LNBs. Additionally, it is possible to increment by 1V (typ.) the selected voltage value to compensate for the excess voltage drop along the coaxial cable (LLC bit HIGH). In order to minimise the power dissipation, the output voltage of the internal step-up converter is adjusted to allow the linear regulator to work at minimum dropout. Another bit of the SR is addressed to the remote control of non-DiSEqC LNBs: the TEN (Tone ENable) bit. When it is set to HIGH, a continuous 22KHz tone is generated regardless of the DSQIN pin logic status. The TEN bit must be set LOW when the DSQIN pin is used for DiSEqC $^{\text{TM}}_{-}$ encoding. The fully bi-directional DiSEqCTM interfacing is completed by the built-in 22KHz tone detector. Its input $\,$ pin (DETIN) must be AC coupled to the DiSEqC TM bus, and the extracted PWK data are available on the DSQOUT pin (*).

In order to improve design flexibility and to allow implementation of newcoming LNB remote control standards, an analogic modulation input pin is available (EXTM). An appropriate DC blocking

capaci-tor must be used to couple the modulating signal source to the EXTM pin. When external modulation is not used, the relevant pin can be left open.

The current limitation block has two thresholds that can be selected by the I_{SEL} bit of the SR; the lower threshold is between 400 and 550mA (I_{SEL} =HIGH), while the higher threshold is between 500 and 650mA (I_{SEL} =LOW).

The current protection block is SOA type. This limits the short circuit current (lsc) typically at 200mA with I_{SEL} =HIGH and at 300mA with I_{SEL} =LOW when the output port is connected to ground.

It is possible to set the Short Circuit Current protection either statically (simple current clamp) or dy-namically by the PCL bit of the SR; when the PCL (Pulsed Current Limiting) bit is set to LOW, the overcurrent protection circuit works dynamically: as soon as an overload is detected, the output is shut-down for a time toff, typically 900ms. Simultaneously the OLF bit of the System Register is set to HIGH. After this time has elapsed, the output is resumed for a time $t_{on}=1/$ $10t_{off}$ (typ.). At the end of t_{on} , if the overload is still detected, the protection circuit will cycle again through Toff and Ton. At the end of a full Ton in which no overload is detected, normal operation is resumed and the OLF bit is reset to LOW. Typical Ton+Toff time is 990ms and it is determined by an internal timer. This dynamic operation can greatly reduce the power dissipation in short circuit condition, still ensuring excellent power-on start up in most conditions (**).

However, there could be some cases in which an highly capacitive load on the output may cause a difficult start-up when the dynamic protection is chosen. This can be solved by initiating any power start-up in static mode (PCL=HIGH) and then switching to the dynamic mode (PCL=LOW) after a chosen amount of time. When in static mode, the OLF bit goes HIGH when the current clamp limit is reached and returns LOW when the overload condition is cleared.

This IC is also protected against overheating: when the junction temperature exceeds 150°C (typ.), the step-up converter and the linear regulator are shut off, the loop-trough switch is opened, and the OTF bit of the SR is set to HIGH. Normal operation is resumed and the OTF bit is reset to LOW when the junction is cooled down to 140°C (typ.).

(*): External components are needed to comply to bi-directional DiSEqCTM bus hardware require-ments. Full compliance of the whole application to DiSEqCTM specifications is not implied by the use of this IC.

(**): The current limitation circuit has no effect on the loop-through switch. When EN bit is LOW, the current flowing from LT1 to LT2 must be externally limited.

ORDERING CODES

TYPE	SO-20 (Tube)	SO-20 (Tape & Reel)	PowerSO-20 (Tube)	PowerSO-20 (Tape & Reel)
LNBP21	LNBP21D2	LNBP21D2-TR	LNBP21PD	LNBP21PD-TR

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Input Voltage	16	V
$V_{\sf UP}$	DC Input Voltage	25	V
V_{LT1}, V_{LT2}	DC Input Voltage	20	V
Io	Output Current	Internally Limited	mA
Vo	DC Output Pin Voltage	-0.3 to 22	V
V _I	Logic Input Voltage (SDA, SCL, DSQIN)	-0.3 to 7	V
V _{DETIN}	Detector Input Signal Amplitude	2	V _{PP}
V _{OH}	Logic High Output Voltage (DSQOUT)	7	V
I _{LT}	Bypass Switch ON Current	900	mA
V _{LT}	Bypass Switch OFF Voltage	±20	V
I _{GATE}	Gate Current	±400	mA
V _{SENSE}	Current Sense Voltage	-0.3 to 1	V
V _{ADDRESS}	Address Pin Voltage	-0.3 to 7	V
T _{stg}	Storage Temperature Range	-40 to +150	°C
T _{op}	Operating Junction Temperature Range	-40 to +125	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

THERMAL DATA

Symbol	Parameter	SO-20	PowerSO-20	Unit
R _{thj-case}	Thermal Resistance Junction-case	15	2	°C/W

PIN CONFIGUARATION (top view)

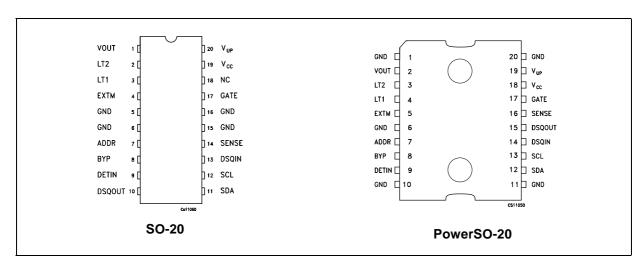
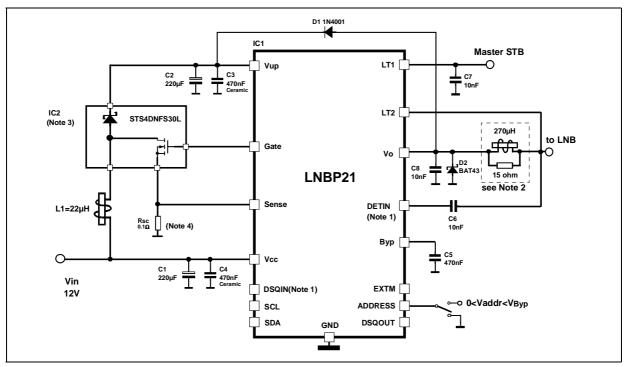


TABLE A: PIN CONFIGURATIONS

SYMBOL	NAME	FUNCTION		JMBER CKAGE
			SO-20	PowerSO-20
V _{CC}	Supply Input	8V to 15V supply. A 220µF bypass capacitor to GND with a 470nF (ceramic) in parallel is recommended	19	18
GATE	Exrernal Switch Gate	External MOS switch Gate connection of the step-up converter	17	17
SENSE	Current Sense Input	Current Sense comparator input. Connected to current sensing resistor	14	16
V _{up}	Step-up Voltage	Input of the linear post-regulator. The voltage on this pin is monitored by internal step-ut controller to keep a minimum dropout across the linear pass transistor	20	19
OUT	Output Port	Output of the linear post regulator modulator to the LNB. See truth table for voltage selections.	1	2
SDA	Serial Data	Bidirectional data from/to I ² C bus.	11	12
SCL	Serial Clock	Clock from I ² C bus.	12	13
DSQIN	DiSEqC Input	When the TEN bit of the System Register is LOW, this pin will accept the DiSEqC code from the main µcontroller. The LNBP21 will use this code to modulate the internally generated 22kHz carrier. Set to GND thi pin if not used.	13	14
DETIN	Detector In	22kHz Tone Detector Input. Must be AC coupled to the DiSEcQ bus.	9	9
DSQOUT	DiSEqC Output	Open collector output of the tone Detector to the main μcontroller for DiSEcQ data decoding. It is LOW when tone is detected.	10	15
EXTM	Extrernal Modulator	External Modulation Input. Need DC decoupling to the AC source. If not used, can be left open.	4	5
GND	Ground	Circuit Ground. It is internally connected to the die frame for heat dissipation.	5, 6, 15, 16	1, 10, 11, 20
BYP	Bypass Capacitor	Needed for internal preregulator filtering	8	8
LT1	Loop Through Switch	In standby mode the power switch between LT1 and LT2 is closed. Max allowed current is 900mA. this pin can be left open if loopthrough function is not needed.	3	4
LT2	Loop Through Switch	Same as above	2	3
ADDR	Address Setting	Four I ² C bus addresses available by setting the Address Pin level voltage	7	7

TYPICAL APPLICATION CIRCUIT



(*) Set to GND if not used

(*) filter to be used according to EUTELSAT reccomendation to implement the DiSEqCTM 2.x, not needed if bidirectional DiSEqCTM 2.x is not implemented (see DiSEqC implementation note) (***) IC2 is a ST Fettky, STS4DNFS30L, that includes both the schottky diode and the N-Channel Mos-Fet, needed for the DC/DC converter,

in a So-8 package. It can be replaced by a schottky diode (STPS2L3A or similar) and a N-Channel Mos-Fet (STN4NF03L or similar)

I²C BUS INTERFACE

Data transmission from main µP to the LNBP21 and viceversa takes place through the 2 wires I2C bus interface, consisting of the two lines SDA and SCL (pull-up resistors to positive supply voltage must be externally connected).

DATA VALIDITY

As shown in fig. 1, the data on the SDA line must be stable during the high period of the clock. The HIGH and LOW state of the data line can only change when the clock signal on the SCL line is LOW.

START AND STOP CONDITIONS

As shown in fig.2 a start condition is a HIGH to LOW transition of the SDA line while SCL is HIGH. The stop condition is a LOW to HIGH transition of the SDA line while SCL is HIGH. A STOP condi-tions must be sent before each START condition.

BYTE FORMAT

Every byte transferred to the SDA line must contain 8 bits. Each byte must be followed by an ac-knowledge bit. The MSB is transferred first.

ACKNOWLEDGE

The master (µP) puts a resistive HIGH level on the SDA line during the acknowledge clock pulse (see fig. 3). The peripheral (LNBP21) acknowledges has to pull-down (LOW) the SDA line during the acknowledge clock pulse, so that the SDA line is stable LOW during this clock pulse. The peripheral which has been addressed has to generate an acknowledge after the reception of each byte, other-wise the SDA line remains at the HIGH level during the ninth clock pulse time. In this case the master transmitter can generate the STOP information in order to abort the transfer. The LNBP21 won't gen-erate the acknowledge if the Vcc supply is below the Undervoltage Lockout threshold (6.7V typ.).

TRANSMISSION WITHOUT ACKNOWLEDGE

Avoiding to detect the acknowledge of the LNBP21, the µP can use a simpler transmission: simply it waits one clock without checking the slave acknowledging, and sends the new data.

This approach of course is less protected from misworking and decreases the noise immunity.

Figure 1 : DATA VALIDITY ON THE I²C BUS

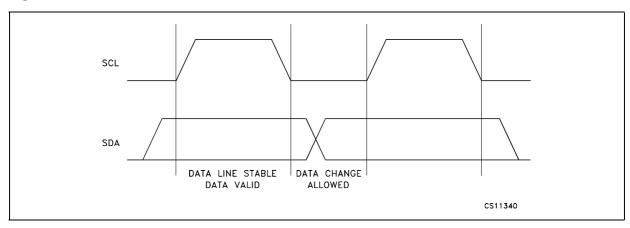


Figure 2 : TIMING DIAGRAM ON I²C BUS

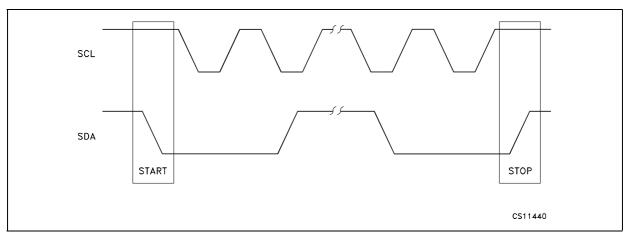
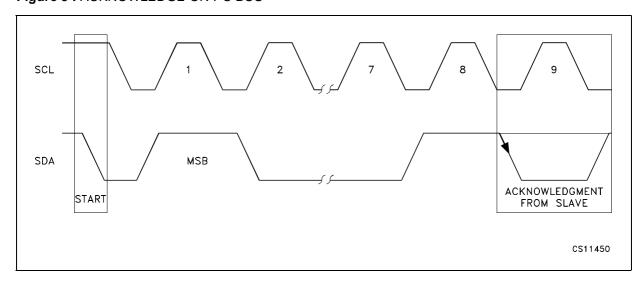


Figure 3 : ACKNOWLEDGE ON I²C BUS



LNBP1 SOFTWARE DESCRIPTION

INTERFACE PROTOCOL

The interface protocol comprises:

- A start condition (S)

- A chip address byte = hex 10 / 11 (the LSB bit determines read(=1)/write(=0) transmission)
- A sequence of data (1 byte + acknowledge)
- A stop condition (P)

			CH	HP AE	DDRE	SS						DA	TΑ				
	MSB							LSB		MSB					LSB		
S	0	0	0	1	0	0	0	R/W	ACK							ACK	Р

ACK= Acknowledge

S= Start P= Stop R/W= Read/Write

SYSTEM REGISTER (SR, 1 BYTE)

MSB							LSB
R, W	R	R					
PCL	ISEL	TEN	LLC	VSEL	EN	OTF	OLF

R,W= read and write bit R= Read-only bit All bits reset to 0 at Power-On

TRANSMITTED DATA (I²C BUS WRITE MODE) When the R/W bit in the chip address is set to 0, the main µP can write on the System Register

(SR) of the LNBP21 via I²C bus. Only 6 bits out of

the 8 available can be written by the µP, since the re-maining 2 are left to the diagnostic flags, and are read-only.

PCL	ISEL	TEN	LLC	VSEL	EN	OTF	OLF	Function
			0	0	1	Х	Х	V _{OUT} =13V, V _{UP} =16V Loopthrough switch open
			0	1	1	Х	Х	V _{OUT} =18V, V _{UP} =21V Loopthrough switch open
			1	0	1	Х	Х	V _{OUT} =14V, V _{UP} =17V Loopthrough switch open
			1	1	1	Х	Х	V _{OUT} =19V, V _{UP} =22V Loopthrough switch open
		0			1	Χ	Χ	22KHz tone is controlled by DSQIN pin
		1			1	Χ	Χ	22KHz tone is ON, DSQIN pin disabled
	0				1	Х	Χ	I _{OUT(min)} =500mA, I _{OUT(max)} =650mA I _{SC} =300mA
	1				1	Х	Х	I _{OUT(min)} =400mA, I _{OUT(max)} =550mA I _{SC} =300mA
0					1	Х	Χ	Pulsed (dynamic) current limiting is selected
1					1	Х	Х	Static current limiting is selected
X X=don't	Χ	Χ	Χ	Х	0	Χ	Χ	Power blocks disabled, Loopthrough switch closed

X= don't care.
Values are typical unless otherwise specified

RECEIVED DATA (I²C bus READ MODE)

The LNBP21 can provide to the Master a copy of the SYSTEM REGISTER information via I2C bus in read mode. The read mode is Master activated by sending the chip address with R/W bit set to 1. At the following master generated clocks bits, the

LNBP21 issues a byte on the SDA data bus line (MSB transmitted first).

At the ninth clock bit the MCU master can:

- acknowledge the reception, starting in this way the transmission of another byte from the LNBP21;

- no acknowledge, stopping the read mode communication.

While the whole register is read back by the μP , only the two read-only bits OLF and OTF convey di-agnostic informations about the LNBP21.

PCL	ISEL	TEN	LLC	VSEL	EN	OTF	OLF	Function												
					0		T _J <140°C, normal operation													
Thes	These bits are read exactly the same as		These bits are read exactly the same as						nese bits are read exactly the same as					ese bits are read exactly the same as			ne as	1		T _J >150°C, power block disabled, Loothrough switch open
		I _{OUT} <i<sub>OMAX, normal operation</i<sub>																		
							1	I _{OUT} >I _{OMAX} , overload protection triggered												

Values are typical unless otherwise specified

POWER-ON I2C INTERFACE RESET

The I2C interface built in the LNBP21 is automatically reset at power-on. As long as the Vcc stays be-low the UnderVoltage Lockout threshold (6.7V typ.), the interface will not respond to any I2C com-mand and the System Register (SR) is initialised to all zeroes, thus keeping the power blocks disabled. Once the Vcc rises above 7.3V, the I2C interface becomes operative and the SR can be configured by the main μP . This is due to About 500mV of hysteresis provided in the UVL threshold to avoid false retriggering of the Power-On reset circuit.

DISEQCTM IMPLEMENTATION

The LNBP21 helps the system designer to implement the bi-directional (2.x) DiSEqC protocol by al-lowing an easy PWK modulation/demodulation of the 22KHz carrier. The PWK data are exchanged between the LNBP21 and the main μP using logic levels that are compatible with both 3.3 and 5V mi-crocontrollers. This data exchange is made through two dedicated pins, DSQIN and DSQOUT, in or-der to maintain the timing relationships between the PWK data and the PWK modulation as accurate as possible. These two pins should be directly connected to two I/O pins of the μP , thus leaving to the resident firmware the task of encoding and decoding the

PWK data in accordance to the DiSEqC pro-tocol. Full compliance of the system to the specification is thus not implied by the bare use of the LNBP21.

The system designer should also take in consideration the bus hardware requirements, that include the source impedance of the Master Transmitter measured at 22KHz. To limit the attenuation at car-rier frequency, this impedance has to be 15ohm at 22KHz, dropping to zero ohm at DC to allow the power flow towards the peripherals. This can be simply accomplished by the LR termination put on the OUT pin of the LNBP, as shown in the Typical Application Circuit on page 5.

Unidirectional (1.x) DiSEqC and non-DiSEqC systems normally don't need this termination, and the OUT pin can be directly connected to the LNB supply port of the Tuner. There is also no need of Tone Decoding, thus, it is recommended to connect the DETIN and DSQOUT pins to ground to avoid EMI.

ADDRESS PIN

Connecting this pin to GND the Chip I2C interface address is 0001000, but, it is possible to choice among 4 different addresses simply setting this pin at 4 fixed voltage levels (see table on page 10).

ELECTRICAL CHARACTERISTICS FOR LNBP SERIES ($T_J = 0 \text{ to } 85^{\circ}\text{C}$, EN=1, LLC=0, TEN=0, ISEL=0, PCL=0, DSQIN=0, V_{IN} =12V, I_{OUT} =50mA, unless otherwise specified. See software description section for I²C access to the system register)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V _{IN}	Supply Voltage	I _O = 500 mA TEN=VSEL=LLC	8		15	V	
V _{LT1}	LT1 Input Voltage					20	V
I _{IN}	Supply Current	I _O = 0mA TEN=VSEL=LLC=1	EN=1		20	40	mA
			EN=0		2.5	5	mA
Vo	Output Voltage	I _O = 500 mA VSEL=1	LLC=0	17.3	18	18.7	V
			LLC=1		19		V

Symbol	Parameter	Test Conditio	ns	Min.	Тур.	Max.	Unit
Vo	Output Voltage	I _O = 500 mA VSEL=0	LLC=0	12.5	13	13.5	V
			LLC=1		14		V
ΔV_{O}	Line Regulation	V _{IN1} =15 to 18V	VSEL=0		5	40	mV
			VSEL=1		5	60	mV
ΔV_{O}	Load Regulation	VSEL=0 or 1 I _{OUT} = 50 to 5	00mA			200	mV
I _{MAX}	Output Current Limiting		ISEL=1	400		550	mA
			ISEL=0	500		650	mA
I _{SC}	Output Short Circuit Current		ISEL=1		200		mA
			ISEL=0		300		mA
t _{OFF}	Dynamic Overload protection OFF Time	PCL=0 Output Shorte	ed		900		ms
t _{ON}	Dynamic Overload protection ON Time	PCL=0 Output Shorte	ed		t _{OFF} /10		ms
f _{TONE}	Tone Frequency	TEN=1		20	22	24	KHz
A _{TONE}	Tone Amplitude	TEN=1		0.55	0.72	0.9	Vpp
D _{TONE}	Tone Duty Cycle	TEN=1		40	50	60	%
t _r , t _f	Tone Rise and Fall Time	TEN=1		5	10	15	μs
G _{EXTM}	External Modulation Gain	$\Delta V_{OUT}/\Delta V_{EXTM}$, f = 10H	z to 40KHz		6		•
V _{EXTM}	External Modulation Input Voltage	AC Coupling				400	mVpp
Z _{EXTM}	External Modulation Impedance	f = 10Hz to 50KHz			260		Ω
V _{LT}	Loopthrough Switch Voltage Drop (lt1 to LT2)	EN=0, I _{LT} =300mA,	V _{MI} =12 or 19V		0.35	0.6	V
f _{SW}	DC/DC Converter Switch Frequency				220		kHz
f _{DETIN}	Tone Detector Frequency Capture Range	0.4Vpp sinewave		18		24	kHz
V _{DETIN}	Tone Detector Input Amplitude	f _{IN} =22kHz sinewave		0.2		1.5	Vpp
Z _{DETIN}	Tone Detector Input Impedance				150		kΩ
V _{OL}	Overload Flag Pin Logic LOW	Tone present I _{OL} =2m	ıA		0.3	0.5	V
I _{OZ}	Overload Flag Pin OFF State Leakage Current	Tone absent $V_{OH} = 0$	6V			10	μΑ
V _{IL}	DSQIN Input Pin Logic LOW					0.8	V
V _{IH}	DSQIN Input Pin Logic HIGH			2			V
I _{IH}	DSQIN Pins Input Current	V _{IH} = 5V			15		μΑ
I _{OBK}	Output Backward Current	EN=0 V _{OBK} = 18V			-4	-10	mA
T _{SHDN}	Temperature Shutdown Threshold				150		°C
ΔT_{SHDN}	Temperature Shutdown Hysteresis				15		°C
	Threshold Temperature Shutdown						_

GATE AND SENSE ELECTRICAL CHARACTERISTICS (T $_J$ = 0 to 85°C, V_{IN} =12V)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
R _{DSON-L}	Gate LOW R _{DSON}	I _{GATE} =-100mA		4.5		Ω
R _{DSON-H}	Gate LOW R _{DSON}	I _{GATE} =100mA		4.5		Ω
V _{SENSE}	Current Limit Sense Voltage			200		mV

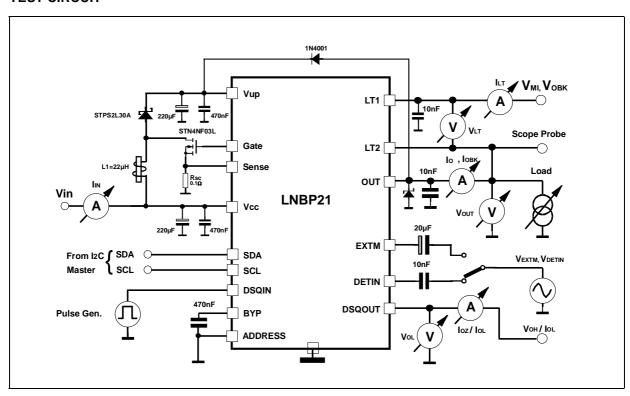
I^2C ELECTRICAL CHARACTERISTICS (T_J = 0 to 85°C, V_{IN}=12V)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IL}	LOW Level Input Voltage	SDA, SCL			0.8	V
V _{IH}	HIGH Level Input Voltage	SDA, SCL	2			V
I _{IH}	Input Current	SDA, SCL, V _{IN} = 0.4 to 4.5v	-10		10	μΑ
V _{IL}	DSQIN Input Pin Logic LOW	SDA (open drain), I _{OL} = 6mA			0.6	V
f _{MAX}	Maximum Clock Frequency	SCL	500			KHz

ADDRESS PIN CHARACTERISTICS (T $_J$ = 0 to 85°C, V_{IN} =12V)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{ADDR-1}	"0001000" Addr Pin Voltage		0		0.7	V
V _{ADDR-2}	"0001001" Addr Pin Voltage		1.3		1.7	V
V _{ADDR-3}	"0001010" Addr Pin Voltage		2.3		2.7	V
V _{ADDR-4}	"0001011" Addr Pin Voltage		3.3		5	V

TEST CIRCUIT



TYPICAL CHARACTERISTICS (unless otherwise specified $T_i = 25$ °C)

Figure 4 : Output Voltage vs Temperature

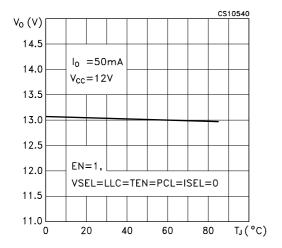


Figure 5 : Output Voltage vs Temperature

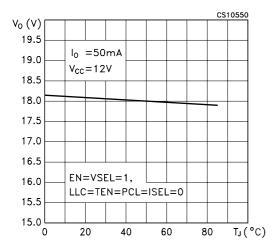


Figure 6: Line Regulation vs Temperature

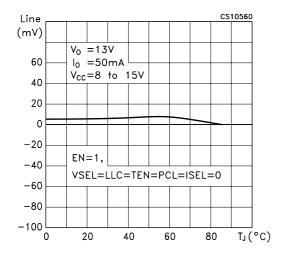


Figure 7: Line Regulation vs Temperature

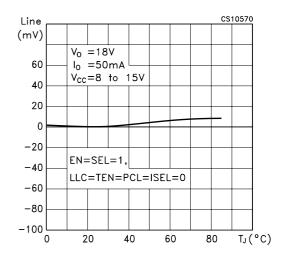


Figure 8 : Load Regulation vs Temperature

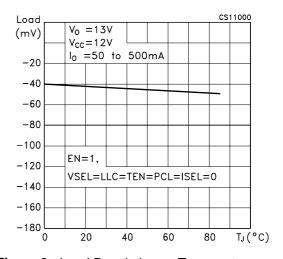


Figure 9: Load Regulation vs Temperature

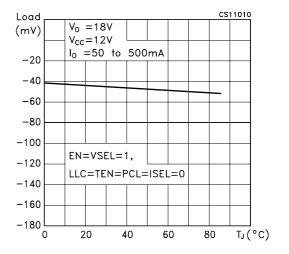


Figure 10: Supply Current vs Temperature

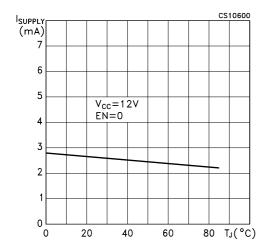


Figure 11: Supply Current vs Temperature

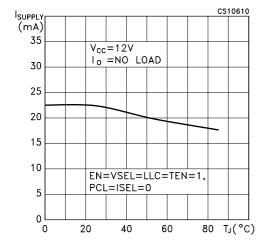


Figure 12 : Dynamic Overload Protection ON Time vs Temperature

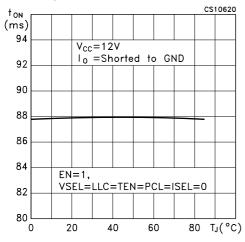


Figure 13 : Dynamic Overload Protection OFF Time vs Temperature

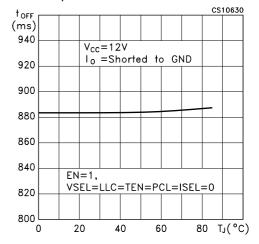


Figure 14 : Output Current Limiting vs Temperature

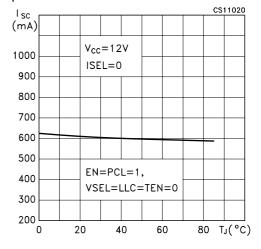


Figure 15 : Output Current Limiting vs Temperature

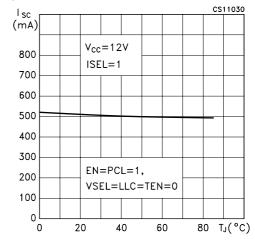


Figure 16: Tone Frequency vs Temperature

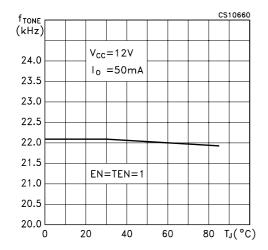


Figure 17: Tone Amplitude vs Temperature

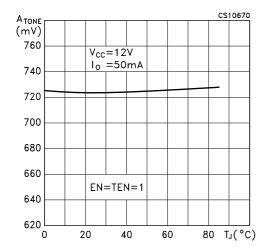


Figure 18: Tone Duty Cicle vs Temperature

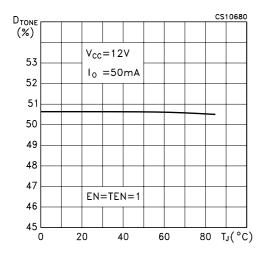


Figure 19: Tone Rise Time vs Temperature

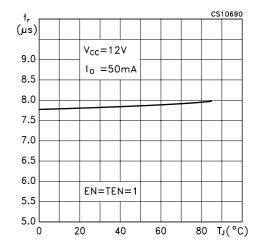


Figure 20 : Tone Fall Time vs Temperature

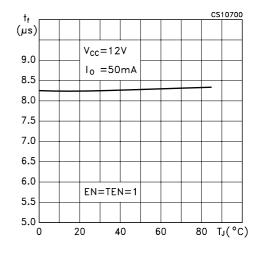


Figure 21 : Loopthrought Switch Drop Voltage vs Temperature

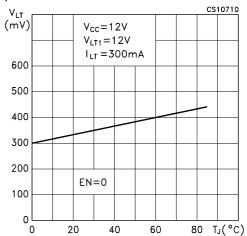


Figure 22 : Loopthrought Switch Drop Voltage vs Temperature

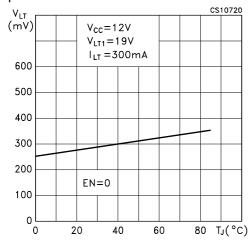


Figure 23 : Loopthrought Switch Drop Voltage vs Loopthrought Current

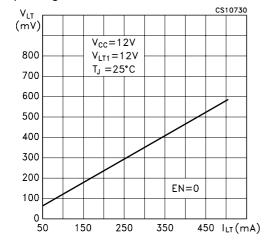


Figure 24 : Loopthrought Switch Drop Voltage vs Loopthrought Current

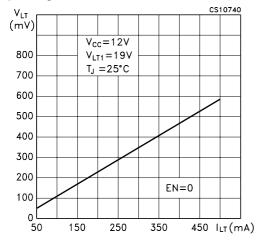


Figure 25 : DSQOUT Pin Logic Low vs Temperature

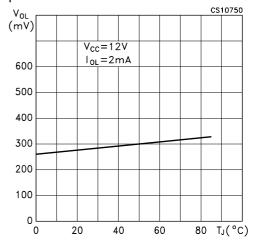


Figure 26 : Undervoltage Lockout Threshold vs Temperature

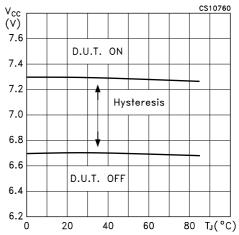


Figure 27 : Output Backward Current vs Temperature

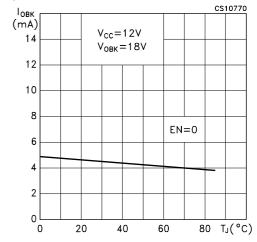


Figure 28 : DC/DC Converter Efficiency vs Temperature

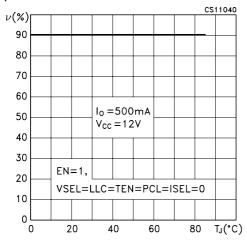


Figure 29 : Current Limit Sense vs Temperature

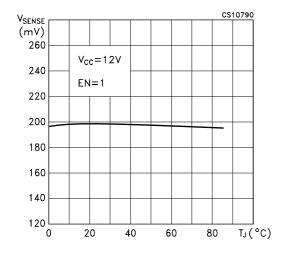


Figure 30: 22kHz Tone

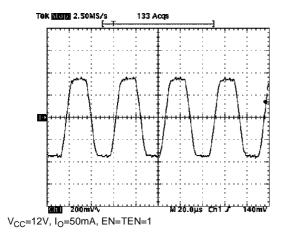
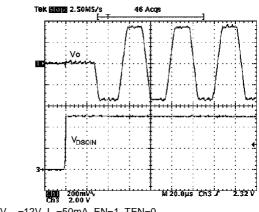
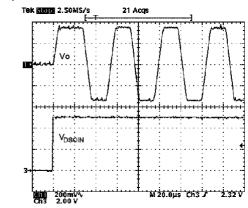


Figure 31: DSQIN Tone Enable Transient Response



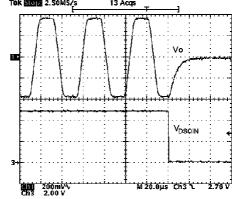
 V_{CC} =12V, I_O =50mA, EN=1, TEN=0

Figure 32 : DSQIN Tone Enable Transient Response



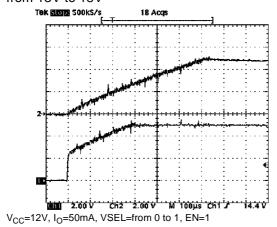
 V_{CC} =12V, I_O =50mA, EN=1, TEN=0

Figure 33 : DSQIN Tone Disable Transient Response



 V_{CC} =12V, I_{O} =50mA, EN=1, TEN=0

Figure 34 : Output Voltage Transient Response from 13V to 18V



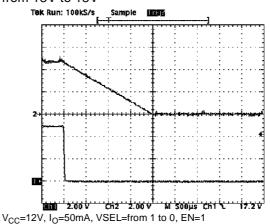
TERMAL DESIGN NOTES

During normal operation, this device dissipates some power. At maximum rated output current (500mA), the voltage drop on the linear regulator lead to a total dissipated power that is of about 1.7W. The heat generated requires a suitable heatsink to keep the junction temperature below the overtemperature protection threshold. Assuming a 40°C temperature inside the Set-Top-Box case, the total Rthj-amb has to be less than 50°C/W.

While this can be easily achieved using a through-hole power package that can be attached to a small heatsink or to the metallic frame of the receiver, a surface mount power package must rely on PCB solutions whose thermal efficiency is often limited. The simplest solution is to use a large, con-tinuous copper area of the GND layer to dissipate the heat coming from the IC body.

The SO-20 package of this IC has 4 GND pins that are not just intended for electrical GND connec-tion, but also to provide a low thermal resistance path between the silicon chip and the PCB heatsink. Given an Rthj-c equal to 15°C/W, a maximum of 35°C/W are left to the PCB heatsink. This figure is achieved if a minimum of 25cm2 copper area is placed just below the IC

Figure 35 : Output Voltage Transient Response from 13V to 18V



body. This area can be the inner GND layer of a multi-layer PCB, or, in a dual layer PCB, an unbroken GND area even on the opposite side where the IC is placed. In both cases, the thermal path between the IC GND pins and the dissipating copper area must exhibit a low thermal resistance.

In figure 4, it is shown a suggested layout for the SO-20 package with a dual layer PCB, where the IC Ground pins and the square dissipating area are thermally connected through 32 vias holes, filled by solder. This arrangement, when L=50mm, achieves an Rthc-a of about 25°C/W.

Different layouts are possible, too. Basic principles, however, suggest to keep the IC and its ground pins approximately in the middle of the dissipating area; to provide as many vias as possible; to de-sign a dissipating area having a shape as square as possible and not interrupted by other copper traces.

Due to presence of an exposed pad connected to GND below the IC body, the PowerSO-20 package has a Rthj-c much lower than the SO-20, only 2°C/W. As a result, much lower copper area must be provided to dissipate the same power and minimum of 12cm2 copper area is enough, see figure 5.

Figure 36: SO-20 SUGGESTED PCB HEATSINK LAYOUT

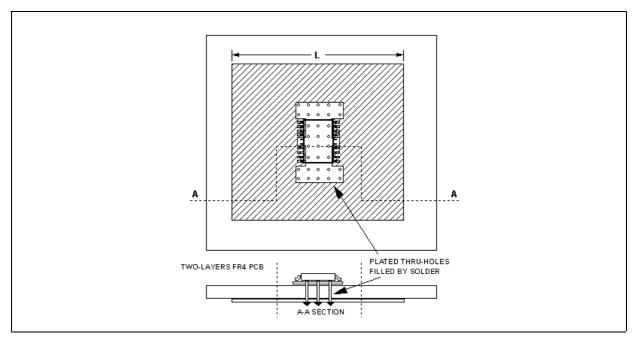
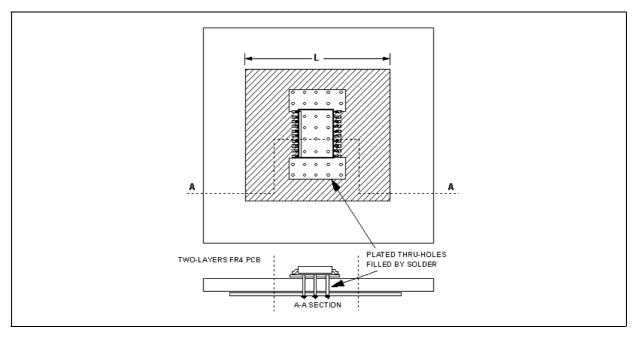
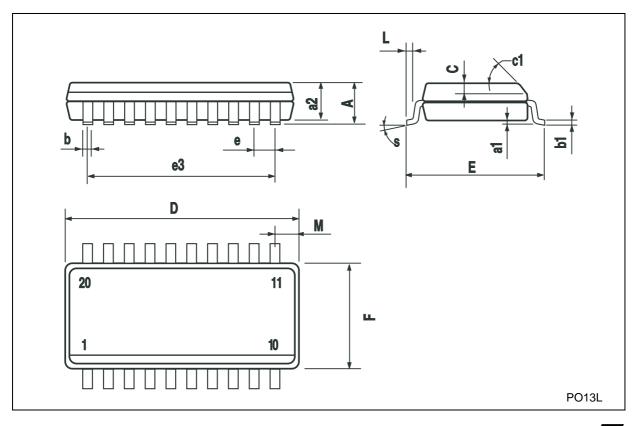


Figure 37: PowerSO-20 SUGGESTED PCB HEATSINK LAYOUT



SO-20 MECHANICAL DATA

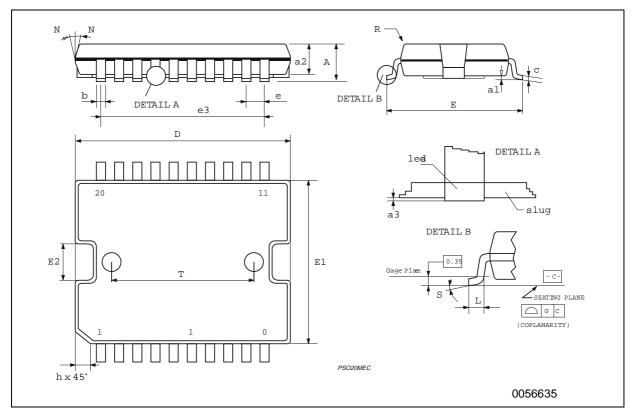
DIM	mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			2.65			0.104
a1	0.1		0.2	0.004		0.008
a2			2.45			0.096
b	0.35		0.49	0.014		0.019
b1	0.23		0.32	0.009		0.012
С		0.5			0.020	
c1	45° (typ.)					
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
е		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.300
L	0.50		1.27	0.020		0.050
М			0.75			0.029
S	8° (max.)					



PowerSO-20 MECHANICAL DATA

DIM	mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			3.60			0.1417	
a1	0.10		0.30	0.0039		0.0118	
a2			3.30			0.1299	
a3	0		0.10	0		0.0039	
b	0.40		0.53	0.0157		0.0209	
С	0.23		0.32	0.0090		0.0013	
D (1)	15.80		16.00	0.6220		0.630	
E	13.90		14.50	0.5472		0.5710	
е		1.27			0.0500		
e3		11.43			0.4500		
E1 (1)	10.90		11.10	0.4291		0.4370	
E2			2.90			0.1141	
G	0		0.10	0.0000		0.0039	
h			1.10			0.0433	
L	0.80		1.10	0.0314		0.0433	
N			10°			10°	
S	0°		8°	0°		8°	
Т		10.0			0.3937		

(1) "D and E1" do not include mold flash or protusions - Mold flash or protusions shall not exceed 0.15mm (0.006")



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